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CORRECTION

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Correction: How fast do defects migrate in halide perovskites: insights from on-the-fly machine-learned force fields

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Correction for 'How fast do defects migrate in halide perovskites: insights from on-the-fly machine-learned force fields' by Mike Pols *et al.*, *Chem. Commun.*, 2023, **59**, 4660–4663, https://doi.org/10.1039/D3CC00953J.

The authors regret that there was an error in the units listed for the reported diffusion parameters shown in Table 1, header row, column 3 of the original article. D_0 ($\times 10^{-6}$ s) should read D_0 ($\times 10^{-6}$ cm^2 s^{-1}). The correct units are shown in the updated table below.

Table 1 Overview of the diffusion parameters D_0 and E_a for halide vacancies (V_X) and halide interstitials (I_X) in $CsPbI_3$ and $CsPbBr_3$

Perovskite	Defect	D_0 ($\times 10^{-6}$ cm^2 s^{-1})	E_a (eV)
$CsPbI_3$	V_I	0.7 ± 0.5	0.34 ± 0.04
$CsPbI_3$	I_I	2.2 ± 1.0	0.20 ± 0.02
$CsPbBr_3$	V_{Br}	0.1 ± 0.2	0.29 ± 0.06
$CsPbBr_3$	I_{Br}	2.0 ± 0.5	0.21 ± 0.01

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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